# Translation

## PATENT COOPERATION TREATY

# **PCT**

### INTERNATIONAL PRELIMINARY REPORT ON PATENTABILITY

(Chapter II of the Patent Cooperation Treaty)

(PCT Article 36 and Rule 70)

			,						
Applicant's or agent's file reference  B 14284.3 CS			FOR FURTHER ACTION		See Form PCT/IPEA/416				
International application No.			International filing da	ate (day/month/year)	Priority date (day/month/year)				
			27.04.200	4	29.04.2003				
International Patent Classification (IPC) or national classification and IPC									
Applicant  COMMISSARIAT A L'ENERGIE ATOMIQUE									
I.	<ol> <li>This report is the international preliminary examination report, established by this International Preliminary Examining Authority under Article 35 and transmitted to the applicant according to Article 36.</li> </ol>								
2.	This REPORT consists of a total of sheets, including this cover sheet.								
3.	3. This report is also accompanied by ANNEXES, comprising:								
				reau) a total of					
	sheets of the description, claims and/or drawings which have been amended and are the basis for this report and/or sheets containing rectifications authorized by this Authority (see Rule 70.16 and Section 607 of the Administrative Instructions).								
	sheets which supersede earlier sheets, but which this Authority considers contain an amendment that goes beyond the disclosure in the international application as filed, as indicated in item 4 of Box No. I and the Supplemental								
i	Box.  b. (sent to the International Bureau only) a total of (indicate type and number of electronic carrier(s))								
	•				containing a sequence listing and/or tables				
, containing a sequence listing and/or tables related thereto, in computer readable form only, as indicated in the Supplemental Box Relating to Sequence Listing (see Section 802 of the Administrative Instructions).									
4.	This report contains	s indications relati	ng to the following iter	ns:					
	Box No. I	Basis of the	report						
	Box No. II	Priority							
	Box No. III	l Non-establi	shment of opinion with	regard to novelty, invent	tive step and industrial applicability				
	Box No. IV	Lack of uni	ty of invention						
	Box No. V		atement under Article d explanations supporti		elty, inventive step or industrial applicability;				
	Box No. VI Certain documents cited								
	Box No. VI	II Certain defe	ects in the international	application					
	Box No. VIII Certain observations on the international application								
Date of submission of the demand				Date of completion of th	uis report				
Name and mailing address of the IPEA/EP				Authorized officer					
Facsimile No.				Telephone No.					

### INTERNATIONAL PRELIMINARY REPORT ON PATENTABILITY

International application No.

PCT/FR2004/050173

Вох	No. I	Basis of the report						
1.		regard to the language, this report is based on the internati ated under this item.	onal application in the language in which it was filed, unless otherwise					
This report is based on translations from the original language into the following language which is the language of a translation furnished for the purposes of:								
		international search (Rule 12.3 and 23.1(b))						
		publication of the international application (Rule 12.	4)					
		international preliminary examination (Rule 55.2 and	d/or 55.3)					
2.	recei	ith regard to the elements of the international application, this report is based on (replacement sheets which have been furnished to the ceiving Office in response to an invitation under Article 14 are referred to in this report as "originally filed" and are not annexed to is report):						
	Ц	the international application as originally filed/furnished						
	$\bowtie$	the description:						
		pages 1-24	as originally filed/furnished					
		pages*	received by this Authority on					
		pages*	received by this Authority on					
	$\boxtimes$	the claims:						
		nos. 1-20	as originally filed/furnished					
		nos.*	as amended (together with any statement) under Article 19					
		nos.*	received by this Authority on					
		nos.*	received by this Authority on					
	$\boxtimes$	the drawings:	·					
		sheets _ 1/8-8/8	as originally filed/furnished					
		sheets*	received by this Authority on					
		sheets*	received by this Authority on					
		a sequence listing and/or any related table(s) - see Suppler						
3.	Ш	The amendments have resulted in the cancellation of:	The amendments have resulted in the cancellation of:					
		the description, pages						
		the claims, nos.						
		the drawings, sheets/figs						
		the sequence listing (specify):						
		any table(s) related to sequence listing (specify):						
4.		This report has been established as if (some of) the amendments annexed to this report and listed below had not been made, since they have been considered to go beyond the disclosure as filed, as indicated in the Supplemental Box (Rule 70.2(c)).						
		the description, pages						
		the claims, nos.						
		the drawings, sheets/figs						
		the sequence listing (specify):						
	any table(s) related to sequence listing (specify):							
*	* If item 4 applies, some or all of those sheets may be marked "superseded."							

### INTERNATIONAL PRELIMINARY REPORT ON PATENTABILITY

International application No.
PCT/FR2004/050173

			nt under Article 35(2) with regard to novelty, inventive step or industrial applicability; anations supporting such statement		
1.	Statement				
	Novelty (N)	Claims	1-20	YES	
		Claims		NO	
	Inventive step (IS)	Claims	1-20	YES	
		Claims	-	NO	
	Industrial applicability (IA)	Claims	1-20	YES	
		Claims		NO	

2. Citations and explanations (Rule 70.7)

Reference is made to the following documents:

D1: US-A-4 927 770 (SWANSON RICHARD M) 22 May 1990 (1990-05-22);

D2: SWANSON R M ET AL: "POINT CONTACT SILICON SOLAR CELLS" IEEE TRANSACTIONS ON ELECTRON DEVICES, IEEE INC. NEW YORK, US, vol. 31, no. 5, May 1984 (1984-05), pages 661-664, XP001080038 ISSN: 0018-9383.

Document D1, which is considered to be the prior art closest to the subject matter of claim 1, describes (the references between parentheses apply to said document):

a method for producing a semiconductor device, comprising the following steps:

 producing, on a first main surface of a semiconductor substrate, a doped area having a first conductivity type and at least one window defining said area (see, for example, D1, figure 2e, area 40 and window); Box No. V Reasoned statement under Article 35(2) with regard to novelty, inventive step or industrial applicability; citations and explanations supporting such statement

- depositing a dielectric film on at least said window and the first metal-coated area (see D1, figure 2h, reference sign 46);
- depositing a first metal-coated area on said doped area (see D1, figure 2f, reference sign 44);
- etching at least a first opening in said
  dielectric film at said window exposing said
  substrate, said opening being intended to
  receive a doped area having a second
  conductivity type, while providing a non-doped
  portion of said semiconductor substrate, at the
  sides of said opening, between said doped area
  having the second conductivity type and said
  doped area having the first conductivity type
  (see D1, figure 2b); and
- doping the substrate leading to said doped area having the second conductivity type (see D1, figures 2d-2h, reference sign 42).

The method in document D1 is also known from document D2.

The subject matter of claim 1 differs from the method in D1 in that the dielectric film is deposited directly inside the window and is in contact with the substrate. It follows that the subject matter of claim 1 is novel (PCT Article 33(2)).

Depositing a dielectric film on at least the

### INTERNATIONAL PRELIMINARY REPORT ON PATENTABILITY

International application No.
PCT/FR2004/050173

Box No. V
Reasoned statement under Article 35(2) with regard to novelty, inventive step or industrial applicability; citations and explanations supporting such statement
window and the metal coating broadens the range of

window and the metal coating broadens the range of metal-coating design options and this results in increased flexibility and reduced production costs for semiconductor devices. As a result, the subject matter of claim 1 is inventive (PCT Article 33(3)).

Claims 2-20 are directly or indirectly dependent on claim 1 and, as such, therefore also fulfil the PCT requirements of novelty and inventive step (PCT Article 33(2) and 33(3)).